

C660-30U

Red LED CHIP

<Specifications>

Commodity Type and Physical Characteristics	
Material	GaAlAs/GaAlAs(DDH)
Top Side N(cathode)side	Au Alloy/Al Pad
Bottom Side P(anode)side	Au Alloy
Electrode Pattern	Fig.1
Chip Size	Fig.2
Chip Thickness	Fig.2
Emission Area	Fig.2

Electro-Optical Characteristics [Ta=25°C]						
Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	Vf	IF=20mA		1.9	2.3	V
Reverse Current	IR	VR=5V			10	uA
Brightness	IV	IF=20mA	40	60		mcd
Power Intensity	PO	IF=20mA	1.0	1.8		mW
Peak Wavelength	λP	IF=20mA	650	660	670	nm
Spectral Radiation Bandwidth	$\Delta\lambda$	IF=20mA		20		nm
Rise Time	tr	IF=20mA		100		ns
Fall Time	tf	IF=20mA		100		ns

Die shall be mounted on TO-18 gold header without resin coated.

[Unit:um]

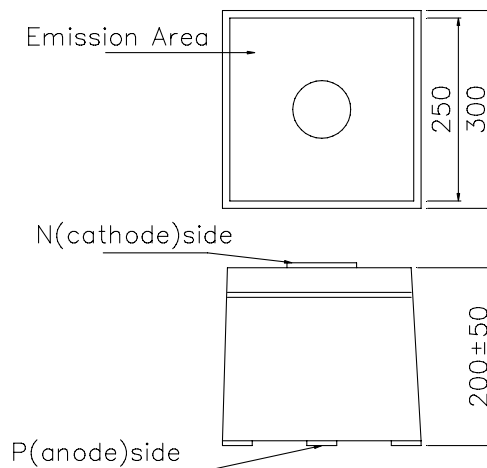
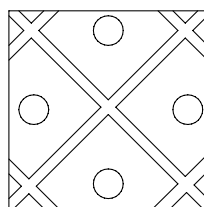
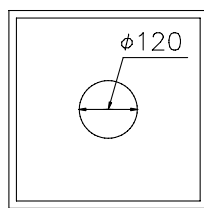


Fig.1 Electrode Pattern

Fig.2 Chip Size and Emission Area